

Two-stage, dual-output, opto-coupled gate driver evaluation board

The SGDR2500P2 is an opto-isolated, two-stage gate driver optimized for high-speed hard switching of Microsemi's APTJC120AM13VCT1AG SiC JFET half-bridge power module. The SGDR2500P2 gate driver provides isolated high-side & low-side drivers with peak output currents of +20/-10 A for fast turn-on transients, yielding record-low switching energy losses.

Features:

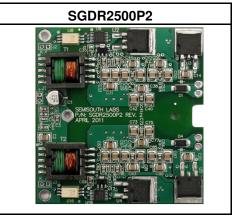
- Suitable for driving Microsemi APTJC120AM13VCT1AG
- Isolated high-side and low-side outputs
- On-board derivation of isolated +/- 15 V supply voltages
- Two-stage driver switching & conduction
- Peak gate current of +20/-10 A
- Switching frequency up to 100 kHz
- Duty cycle: 0 to 100%

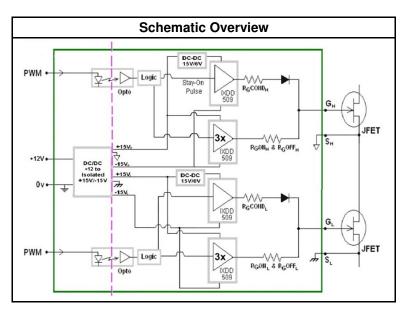
Applications:

- Hard Switched Bridge Topologies
- Inverters/Converters
- Product Evaluation
- Research
- For operation principles and intended use, refer to Application note AN-SS5.

1100	r roduct Summary								
V_{DD}	+12	V							
I _{PK}	+20/-10	A							
$F_{SW(MAX)}$	100	kHz							
Duty Cycle	0-100	%							

Product Summary





MAXIMUM RATINGS

Parameter	Symbol	Conditions	Value	Unit
Positive supply voltage	V _{CC}	to GND	+ 12	V
Input current logic HIGH	I _{F(ON)}	(high and low side inputs)	10	mA
Pack Output Ourrant		Not connected to the JFET, output shorted to GND or pure	+ 27	٨
Peak Output Current	I _O	capacitive load	- 27	A
Operating temperature	T _{OP}		+ 85	°C
Storage temperature	T _{ST}		+ 100	°C

SGDR2500P2 Rev 1.3



ELECTRICAL CHARACTERISTICS

Parameter	Symbol	Symbol Conditions -		Value			
Farameter	Symbol			Min Typ Max		Unit	
External Power Supplies							
Positive supply voltage	V _{CC}	to GND	+ 11.5		+12.5	V	
Depitive gupply gurrent		without load		0.2		m (
Positive supply current	ICC	V _{CC} = +12 V, f = 100 kHz, D = 50%		1400		mA	
Positive supply current I_{CC} $V_{CC} = +12 V$, f = 100 kHz, D = 50% 1400							
Input (characteristics same for b	ooth inputs)						

Input forward voltage	V _F	I _F = 5 mA, T _A = 25 °C	1.4	1.60	1.70	V
Input voltage, OFF	V _{F(OFF)}		0	-	0.8	V
Input current, ON	I _{F(ON)}		4.5	-	10	mA
Input capacitance	C _{in}	$V=0V,f=1~MHz,T_A=25~^{o}C$	-	45	-	pF

Timing Characteristics

Delay time input to output	t _{d(ON)}	-	130	-	ns
Delay time input to output	$t_{\text{d}(\text{OFF})}$	-	130	-	ns

Output (characteristics same for both outputs)

Output voltage	Vo	Peak positive voltage clamped by JFET gate-source diode	- 15	-	+ 5V	V	
Deals autout aumont (1)	1	$R_{GON} = 0.17 \ \Omega$	$R_{GON} = 0.17 \ \Omega$ -			^	
Peak output current ⁽¹⁾	IO	$R_{GOFF} = 0.17 \ \Omega$		- 10	-	A	
Steady-state output current I _{ODC}		limited by R _{GCOND}	-	500		mA	
Output voltage rise time	t _{ro}		-	-	20	ns	
Output voltage fall time	ut voltage fall time t _{fo}		-	-	20	ns	

Electrical Isolation

Creep path input-output		7.6	-	-	mm
Max $\Delta V/\Delta t$ at $\Delta V = TBD$	10 kV used at 1000 Vp-p		TBD		kV/μs

Operating Conditions

Operating Temperature	T _{OP}	0	-	+ 85	°C
Storage Temperature	T _{ST}	0	-	+ 100	°C

Notes:

(1) IPK is limited by the JFET gate-source voltage (VGS) and gate resistor (RG). Pulse width is fixed at 100 ns. Connected to APTJC120AM13VCT1AG.



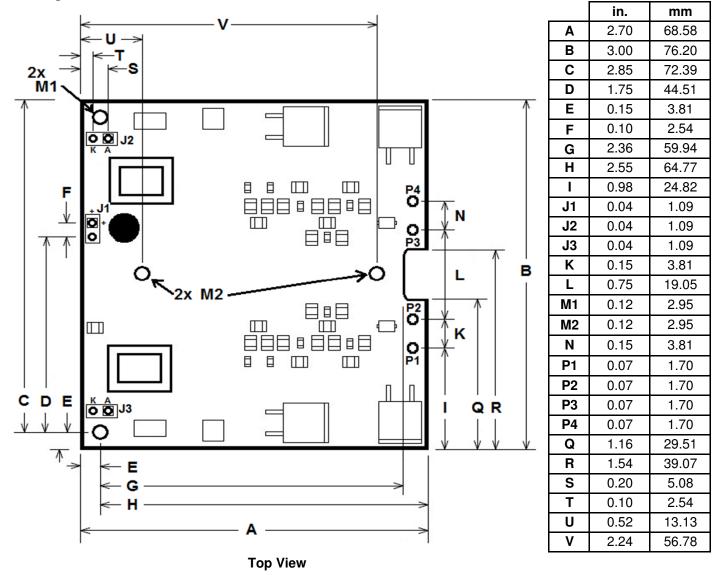
Preliminary

Demo Board SGDR2500P2

Package Pinout

	Pin Descriptions								
J1	VCC	Voltage supply	P1	SL	Low side source connection				
J2	V _H	High side PWM (opto-coupler input)	P2	GL	Low side gate connection				
J3	VL	Low side PWM (opto-coupler input)	P3	G _H	High side gate connection				
			P 4	S _H	High side source connection				

Package Dimensions





Preliminary

Demo Board SGDR2500P2

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